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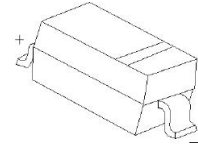
Product data sheet

Silicon Epitaxial Planar Schottky Barrier Diode

for low current rectification and high speed switching applications

FEATURES

- Low current rectifier s
- Low voltage, low inductance
- For power supply



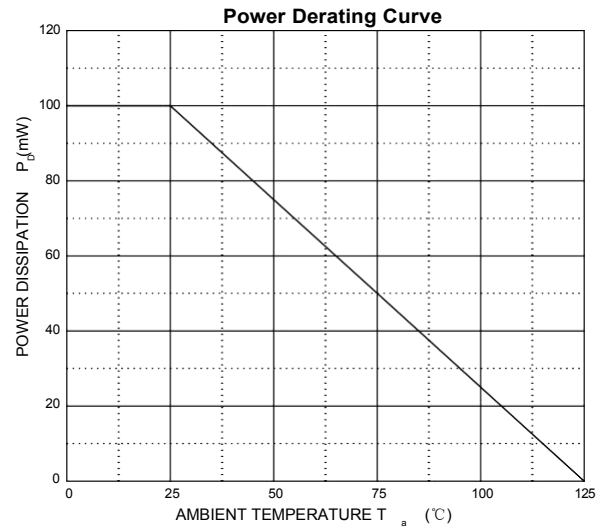
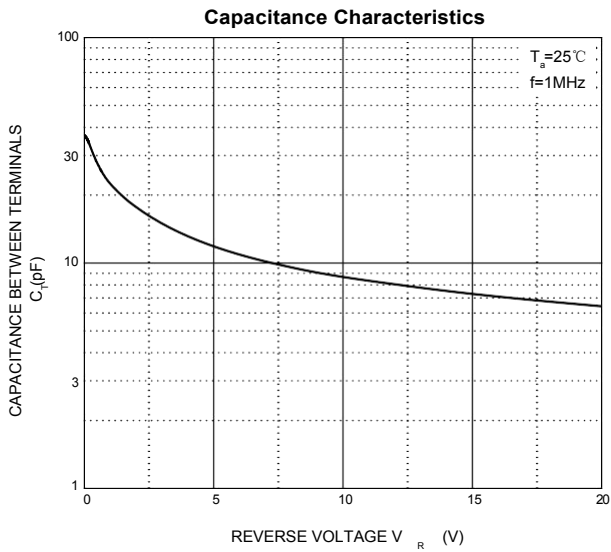
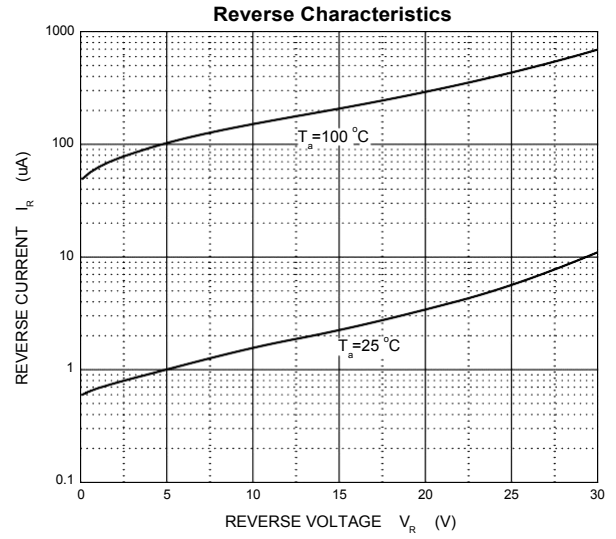
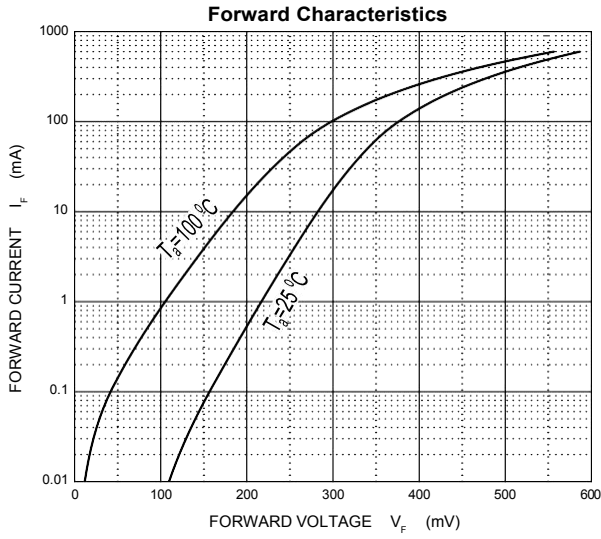
SOD-323

Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C

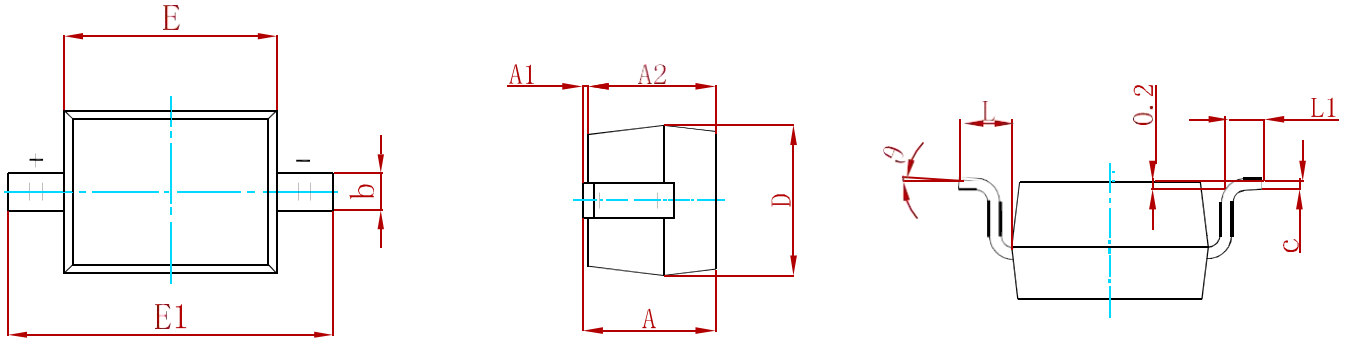
Parameter	Symbol	Limit	Unit
Peak reverse voltage	V_{RM}	30	V
DC reverse voltage	V_R	20	V
Mean rectifying current	I_O	0.5	A
Peak forward surge current	I_{FSM}	2	A
Power dissipation	P_d	250	mW
Thermal resistance junction to ambient	$R_{\theta JA}$	400	°C/W
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	-55~+150	°C

Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V_F			0.36 0.47	V	$I_F=100mA$ $I_F=500mA$
Reverse current	I_R			100	μA	$V_R=20V$

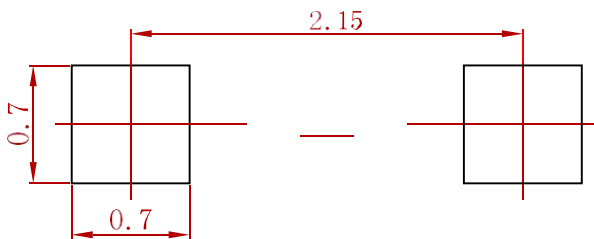


PACKAGE MECHANICAL DATA



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A		1.000		0.039
A1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.031	0.035
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
E	1.600	1.800	0.063	0.071
E1	2.550	2.750	0.100	0.108
L	0.475 REF.		0.019 REF.	
L1	0.250	0.400	0.010	0.016
θ	0°	8°	0°	8°

Suggested Pad Layout



- Note:**
1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05mm.
 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
RB551V-30-MS	SOD-323	3000

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